Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	((first adj Pass/Fail adj signal adj indicative adj2 success adj failure adj3 operation adj outputted) and (each adj cell adj array adj group)). clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/28 12:46
L2	1	makamura-hiroshi.inv.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/28 12:46
L3	0	yamumura-toshio.inv.	US-PGPUB;	OR	ON	2005/11/28 12:47
			USPAT; EPO; JPO; DERWENT; IBM_TDB			
L4	124	yamamura-toshio.inv.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/28 12:47
S1	30086	(memory adj cell adj array)	US-PGPUB;	OR	ON	2005/07/01 16:20
			USPAT; EPO; JPO; DERWENT; IBM_TDB			
S2	8701	S1 and group	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:20
S3	7340	pass/fail or (pass adj fail) or	US-PGPUB;	OR	ON	2005/07/01 16:38
		pass-fail	USPAT; EPO; JPO; DERWENT;			
			IBM_TDB			
S4	7089	S3 and (test\$3 or detect\$3 or monitor\$3 or measur\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:21
S5	3370	S4 and (program or erase)	US-PGPUB; USPAT;	OR	ON	2005/07/01 16:22
			EPO; JPO; DERWENT; IBM_TDB			
S6	432	S5 and EEPROM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:22

S7	128	S6 and NAND	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:22
S8	128	S7 and second	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:23
S9	123	S8 and plurality	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:23
S10	95	S9 and parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:25
S11	47	S10 and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:32
S12	7	S11 and (second adj3 signal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:32
S13	3	S11 and ((pass/fail) adj2 signal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 16:41
S14	7366	pass/fail or (pass adj fail) or pass-fail	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S15	7115	S14 and (test\$3 or detect\$3 or monitor\$3 or measur\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S16	3382	S15 and (program or erase)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45

S17	436	S16 and EEPROM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S18	129	S17 and NAND	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S19	129	S18 and second	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S20	123	S19 and plurality	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S21	95	S20 and parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S22	47	S21 and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S23	3	S22 and ((pass/fail) adj2 signal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S24	7366	pass/fail or (pass adj fail) or pass-fail	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:45
S25	3382	S15 and (program or erase)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:47
S26	6782	365/200	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:47

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S27	182	S15 AND S26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:48
S28	112	S27 and S16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:47
S29	21	S28 and S17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:47
S30	2299	365/185.33	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:48
S31	15	S20 AND S26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:48
S32	1141	365/185.21	US-PGPUB;	OR	ON	2005/07/11 16:48
1 1			USPAT; EPO; JPO;			
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S33	14	S32 and S15	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 16:49
S34	1	makamura-hiroshi.inv.	US-PGPUB;	OR	ON	2005/07/11 16:49
			USPAT; EPO; JPO;	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		
			DERWENT; IBM_TDB			in the second se
S35	121	yamamura-toshio.inv.	US-PGPUB;	OR	ON	2005/07/11 16:50
	121	Jamanara Cosmodilivi	USPAT;		ON	2505/07/11 10.50
			EPO; JPO; DERWENT;			
			IBM_TDB			

GAU: 2824 Classification: 365/201.000

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Status: 71 - RESPONSE TO NON-FINAL OFFICE ACTION ENTERED AND FORWARDED TO EXAMINER
Title: SEMICONDUCTOR MEMORY

All tab report (29 items, not sorted)

ത്തി	Status	DociGode	Document Type	Date	Pages	Annotations
	13	WFEE	Fee Worksheet (PTO-875)	10/28/2005	1	
	13	FWCLM	Index of Claims	10/28/2005	1	
5	7	A	Amendment - After Non-Final Rejection	10/25/2005	2	
	7	CLM	Claims	10/25/2005	သ	
	7	REM	Applicant Arguments or Remarks Made in an Amendment 10/25/2005	10/25/2005	3	
	7	CTNF	Non-Final Rejection	07/25/2005	6	
	7	1449	List of References cited by applicant and considered by examiner	07/25/2005	1	
	7	892	List of references cited by examiner	07/25/2005	1	
	7	FWCLM	Index of Claims	07/25/2005	1	
	7	SRFW	Search information including classification, databases and other search related notes	07/25/2005	-1	
	7	BIB	Bibliographic Data Sheet	.07/25/2005	1	
	7	SRNT	Examiner's search strategy and results	07/11/2005	4	
	7	PEFR	Applicant Response to Pre-Exam Formalities Notice	03/29/2004	2	
	7	OATH	Oath or Declaration filed	03/29/2004	ω	

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Foreign Reference	Foreign Reference	Information Disclosure Statement (IDS) Filed	Application Data Sheet	Fee Worksheet (PTO-875)	Fee Worksheet (PTO-875)	Foreign Priority Papers Filed	Drawings	Abstract	Claims	Specification	Transmittal letter	Pre-Exam Formalities Notice	Application Data Sheet	Document Type
10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	10/29/2003	01/28/2004	03/29/2004	Date:
16	18	3	2	1	1	56	12	1	3	46	2	1	3	(Pages
		CONSIDERED 11/28/05												Annotations

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Authorization for Extension of Time for all replies	Document Type
10/29/2003	Date
2	Pages
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